

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

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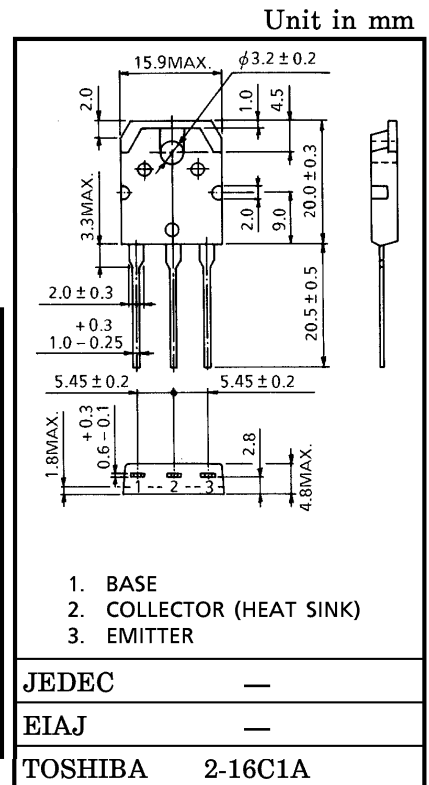
SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING APPLICATIONS.

HIGH SPEED DC-DC CONVERTER APPLICATIONS.

- Excellent Switching Times
: $t_r = 1.0 \mu s$ (Max.), $t_f = 1.0 \mu s$ (Max.) ($I_C = 5A$)
- High Collector Breakdown Voltage : $V_{CEO} = 400V$

MAXIMUM RATINGS ($T_a = 25^\circ C$)

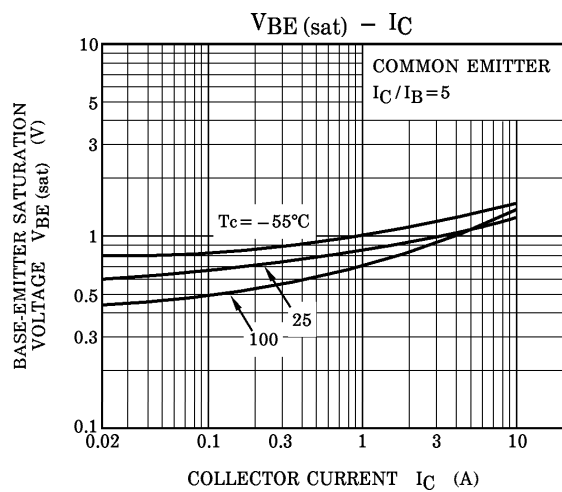
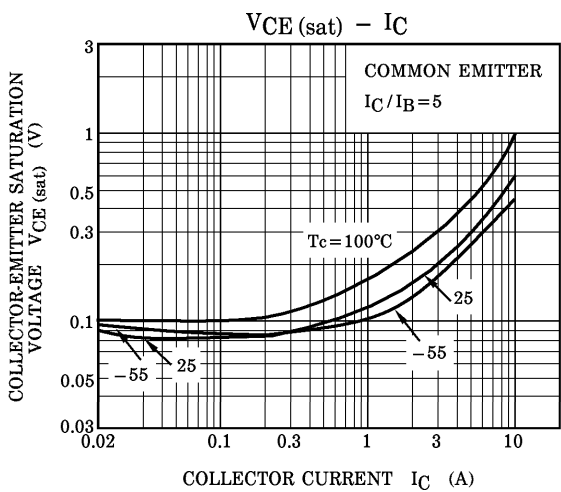
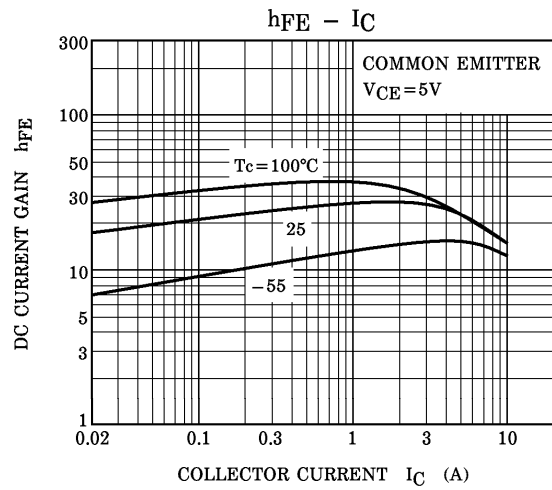
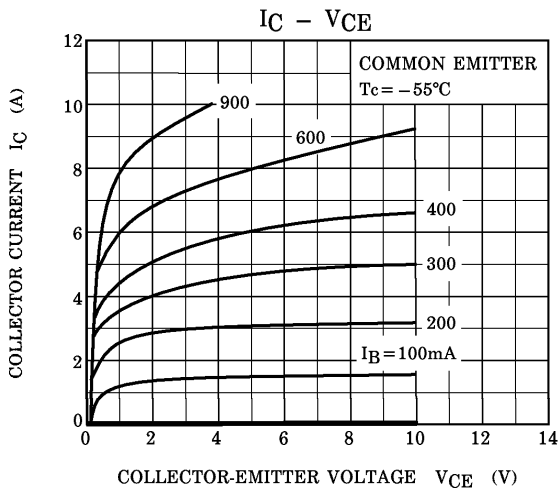
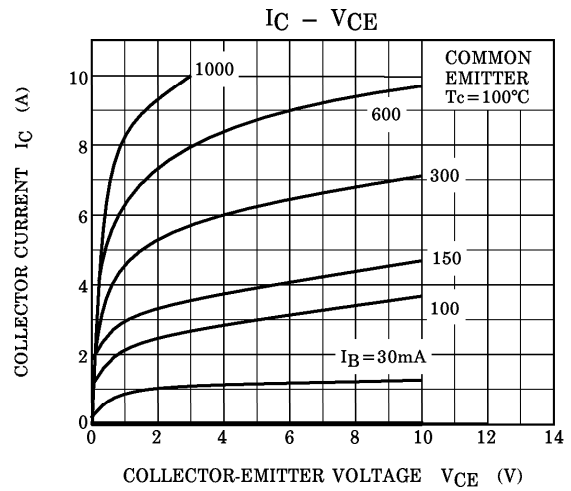
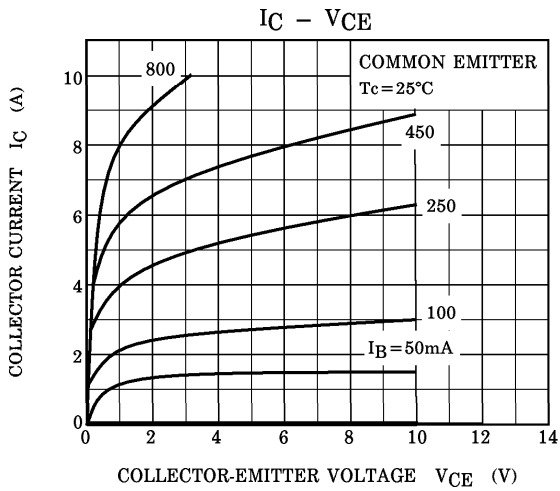
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	500	V
Collector-Emitter Voltage	V_{CEO}	400	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector Current	DC	I_C	10
	Pulse	I_{CP}	15
Base Current	I_B	5	A
Collector Power Dissipation ($T_c = 25^\circ C$)	P_C	100	W
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55~150	$^\circ C$

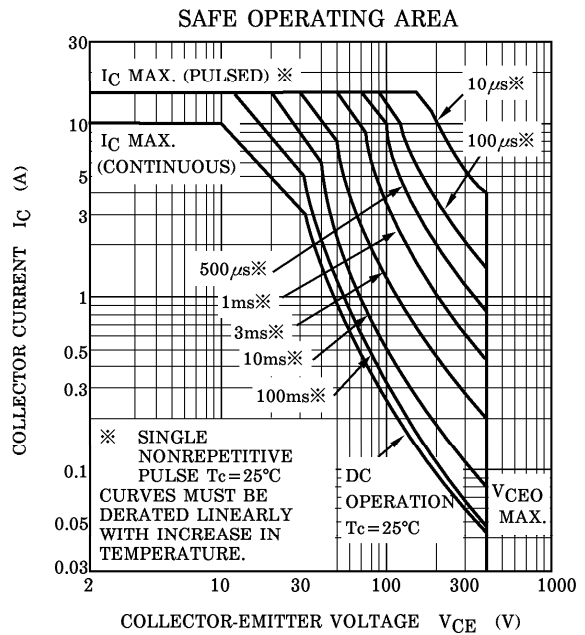
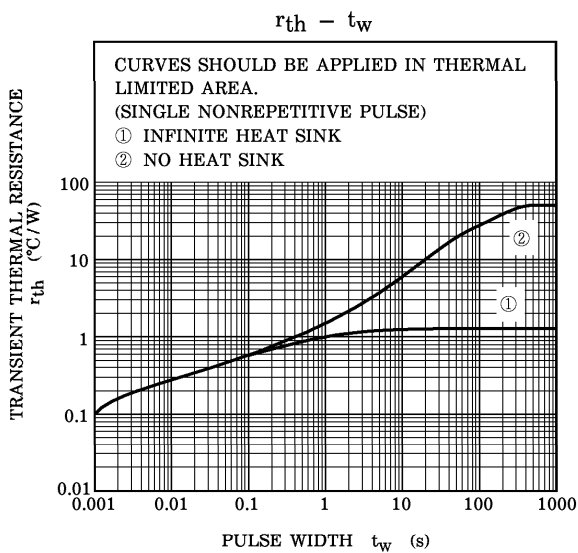
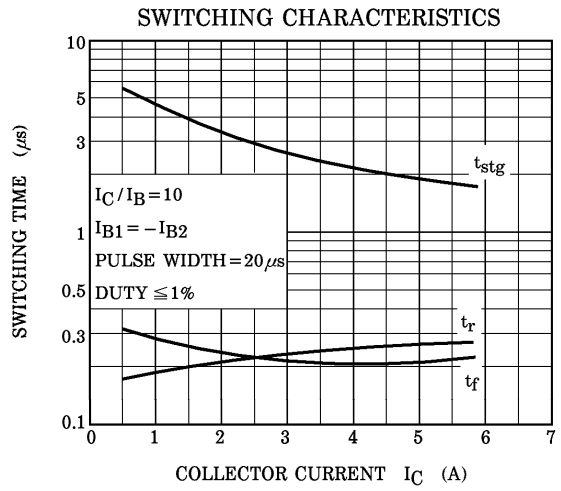
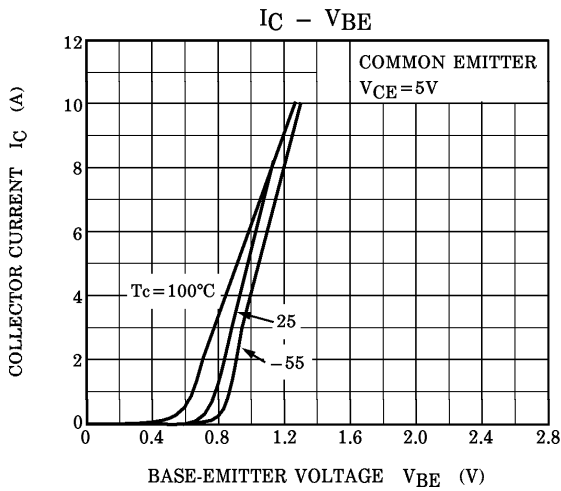


Weight : 4.7g

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Collector Cut-off Current	I_{CBO}	$V_{CB} = 400V, I_E = 0$	—	—	100	μA	
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 7V, I_C = 0$	—	—	1	mA	
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1mA, I_E = 0$	500	—	—	V	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10mA, I_B = 0$	400	—	—	V	
DC Current Gain	h_{FE}	$V_C = 5V, I_C = 5A$	10	—	—		
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 5A, I_B = 0.5A$	—	—	1.5	V	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 5A, I_B = 0.5A$	—	—	2.0	V	
Switching Time	Rise Time	t_r			—	—	1.0
	Storage Time	t_{stg}			—	—	2.5
	Fall Time	t_f			—	—	1.0





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